

Energy and Capacitance

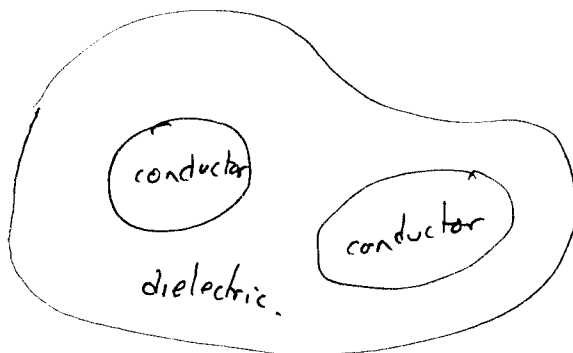
①

With our new field, \vec{D} , how does the potential difference get modified. The electric field is still the force per unit charge, so the work (per charge) to move a charge through an electric field is unchanged

$$\frac{W}{q} = - \int_{\vec{A} \rightarrow \vec{B}} \vec{E} \cdot d\vec{l} = V(\vec{B}) - V(\vec{A})$$

The insertion of a dielectric will modify the potential, but the potential is still calculated from the electric field.

Consider the following system



If charge $+Q$ is introduced on one conductor and charge $-Q$ on the other conductor, a field is produced and a potential difference will

The potential difference measured is proportional to the charge (because the field is proportional). (2)

Capacitance (C)

$$C = \frac{Q}{|\Delta V|}$$

• Units Farads $1 \text{ F} = 1 \frac{\text{C}}{\text{V}}$

• $\epsilon_0 = 8.85 \times 10^{-12} \text{ F/m}$

• Depends only on geometry and constants

⇒ A configuration of conductors has an intrinsic property, capacitance, independent of any fields, charges, etc.

Energy (U) - The energy of a system is the work to build it charge by charge. Let's compute the energy of our conducting blob.

I. Begin with no charge.

II. The work to move a charge dQ is $dW = dQ \Delta V$ where ΔV is the potential difference between the conductors.

The total work and therefore the total energy is

(3)

$$U = W = \int_0^Q \Delta V dQ = C \int Q dQ$$

$$= \frac{1}{2} \frac{Q^2}{C} = \frac{1}{2} Q \Delta V = \frac{1}{2} C (\Delta V)^2$$

• This formula applies to any system that can be viewed as a capacitor, that is one or two equal and opposite surface charges.

• Note, this follows directly from our ~~form~~ potential form of the energy density

$$\frac{1}{2} \rho V$$

since all the charge is at the same potential

$$\frac{1}{2} QV$$

Ex Let's use this to calculate stuff we already know how to do. Consider an isolated spherical conductor with radius R . If it is charged to a charge Q calculate the energy.

(4)

Method I

Since all the charge is at the same potential in reference to ∞ , the energy is

$$U = \frac{1}{2} \int \rho V dv' = \frac{1}{2} QV$$

$$V = \frac{kQ}{R}$$

$$U = \frac{1}{2} Q \left(\frac{kQ}{R} \right) = \frac{1}{2} k \frac{Q^2}{R}$$

Method II Integrate energy density

$$U = \frac{1}{2} \epsilon_0 E^2$$

$$= \frac{E^2}{8\pi k}$$

$$k = \frac{1}{4\pi\epsilon_0}$$

$$\epsilon_0 = \frac{1}{4\pi k}$$

$$E = \frac{kQ}{r^2}$$

$$U = \left(\frac{1}{8\pi k} \right) \left(\frac{kQ}{r^2} \right)^2 = \frac{k}{8\pi} \frac{Q^2}{r^4}$$

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Total Energy

$$U = \int u dv' = \int_R^{\infty} (4\pi r^2 dr) \frac{k}{8\pi} \frac{Q^2}{r^4}$$

using shell method with spherical shell $4\pi r^2 dr$

$$U = \frac{kQ^2}{2} \int_R^{\infty} \frac{dr}{r^2} = -\frac{kQ^2}{2r} \Big|_R^{\infty} = \frac{kQ^2}{2R}$$

Method III Use capacitance



Calculate capacitance of isolated sphere

I. Place Q on sphere

$$\text{II} \quad \vec{E} = \frac{kQ}{r^2} \hat{r}$$

$$\text{III} \quad V = -\int E dr = \frac{kQ}{r} + C$$

⑥

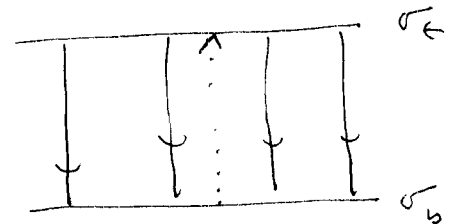
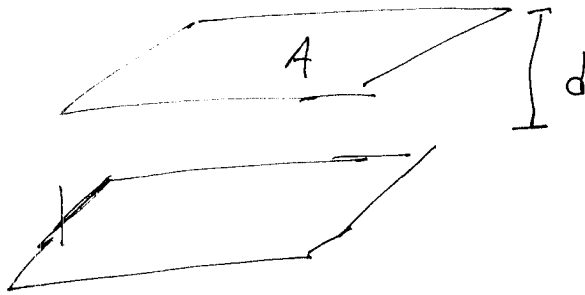
$$\Delta V = \frac{kQ}{R}$$

$$C = \frac{Q}{\Delta V} = \frac{R}{k} = 4\pi\epsilon_0 R$$

Total Energy

$$U = \frac{1}{2} \frac{Q^2}{C} = \frac{1}{2} \frac{Q^2}{4\pi\epsilon_0 R} = \frac{1}{2} \frac{kQ^2}{R}$$

Parallel - Plate Capacitors



I Place $+Q$ on upper plate, $-Q$ on lower plate.

II Charge densities, $\sigma_t = \frac{Q}{A} \equiv \sigma$ $\sigma_b = -\frac{Q}{A}$

III Fields

$$\vec{E} = -\frac{\sigma}{\epsilon_0} \hat{z}$$

$$\text{IV} \quad \Delta V = - \int \vec{E} \cdot d\vec{l} = E d = \frac{\rho}{\epsilon_0} d$$

$$\text{V} \quad C = \frac{Q}{\Delta V} = \frac{\sigma A}{\Delta V} = \frac{\sigma A}{\left(\frac{\sigma}{\epsilon_0} d\right)}$$

$$C = \frac{A \epsilon_0}{d}$$

Alternate derivation of energy density. Consider a parallel-plate capacitor with separation d and area A .

The energy contained in the capacitor is

$$U = \frac{1}{2} C \Delta V^2 = \frac{1}{2} \left(\frac{A \epsilon_0}{d} \right) (\Delta V)^2$$

The energy per unit volume is then

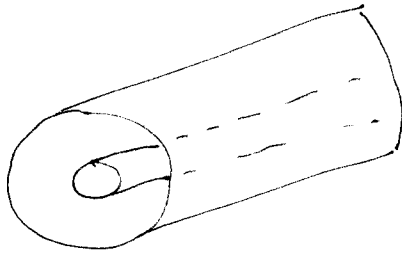
$$u = \frac{U}{V} = \frac{U}{A d} = \frac{1}{2} \epsilon_0 \left(\frac{\Delta V}{d} \right)^2$$

$$\text{but } E = \frac{\Delta V}{d}$$

$$u = \frac{1}{2} \epsilon_0 E^2 \quad \checkmark$$

Cylindrical Capacitors

⑧

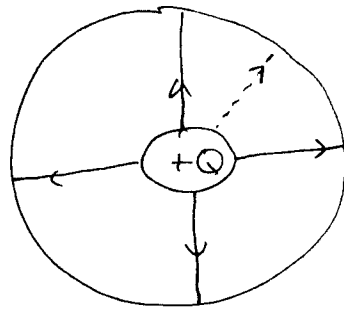


Inner radius r_i

Outer radius r_o

Consider a capacitor of length l .

I. Place $+Q$ on inner conductor, $-Q$ on outer.



II Fields

$$\text{Gauss } \oint \vec{E} \cdot d\vec{A} = 2\pi r l E = \frac{Q_{\text{enc}}}{\epsilon_0} = \frac{Q}{\epsilon_0}$$

$$E = \frac{1}{2\pi \epsilon_0 r} \left(\frac{Q}{l} \right)$$

$$\text{Define } \lambda = \frac{Q}{l}$$

$$E = \frac{\lambda}{2\pi \epsilon_0 r}$$

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$$\Delta V = - \int E dp = - \frac{\lambda}{2\pi\epsilon_0} \int_{r_i}^{r_o} \frac{dp}{p}$$

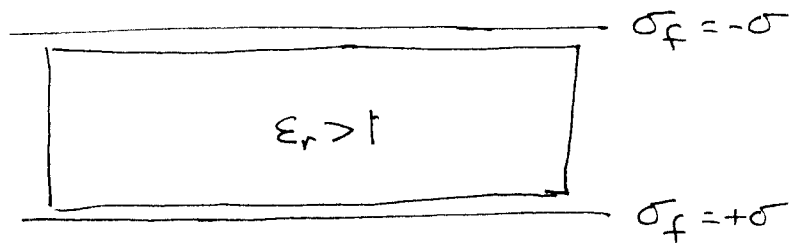
$$= - \frac{\lambda}{2\pi\epsilon_0} \ln\left(\frac{r_o}{r_i}\right)$$

$$|\Delta V| = \frac{\lambda}{2\pi\epsilon_0} \ln\left(\frac{r_o}{r_i}\right)$$

$$C = \frac{Q}{|\Delta V|} = \frac{\lambda l}{|\Delta V|} = \frac{\lambda l}{\frac{\lambda}{2\pi\epsilon_0} \ln\left(\frac{r_i}{r_o}\right)}$$

$$\frac{C}{l} = \frac{2\pi\epsilon_0}{\ln\left(\frac{r_i}{r_o}\right)}$$

Now, add a dielectric to a capacitor. Let's start with a parallel plate capacitor. (10)



I. Add $\pm Q \Rightarrow \sigma_f = \sigma = Q/A$

II. $\vec{D} = \sigma \hat{z}$ as before.

III $\Delta V = - \int \vec{E} \cdot d\vec{s}$ $\vec{E} = \frac{\vec{D}}{\epsilon} = \frac{\sigma}{\epsilon} \hat{z}$

$$= - \frac{\sigma}{\epsilon_0} \int_0^d \frac{\epsilon_0}{\epsilon_r} ds = - \frac{\sigma d}{\epsilon_r}$$

IV $C = \frac{Q}{|\Delta V|} = \frac{\epsilon A}{d} = \frac{\epsilon_r \epsilon_0 A}{d} = \epsilon_r C_0$

\Rightarrow Dielectric increases capacitance by ϵ_r

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Energy Density Parallel Plate

$$u = \frac{U}{V} = \frac{U}{Ad} = \frac{\frac{1}{2} C (\Delta V)^2}{dA}$$

$$= \frac{\frac{1}{2} \left(\frac{\epsilon A}{d} \right) (\Delta V)^2}{dA} = \frac{1}{2} \epsilon_0 \left(\frac{\Delta V}{d} \right)^2$$

$$= \frac{1}{2} \epsilon_0 E^2 = \frac{1}{2} \vec{E} \cdot \vec{D}$$
